



#### 160V NPN SMALL SIGNAL TRANSISTOR IN SOT23

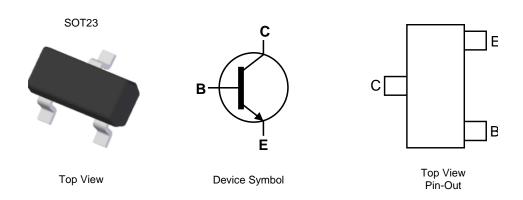
#### **Features**

- BV<sub>CEO</sub> > 160V
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (MMBT5401)
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

An Automotive-Compliant Part is Available Under Separate Datasheet (MMBT5551Q)

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" molding compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)



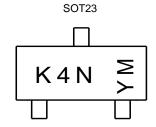
### **Ordering Information** (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBT5551-7-F	K4N	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

### **Marking Information**



K4N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

#### Date Code Key

2010 0000 110	,											
Year	2020	2021	1 20	022	2023	2024	2025	2026	3 20	27	2028	2029
Code	Н	- 1		J	K	L	М	N	(	)	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	180	V
Collector-Emitter Voltage	$V_{CEO}$	160	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current - Continuous (Note 1)	Ic	600	mA

# Thermal Characteristics (@ $T_A = +25$ °C unless otherwise specified)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P <sub>D</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

### Electrical Characteristics @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	180	_	V	$I_C = 100\mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6.0	_	V	$I_E = 10\mu A, I_C = 0$	
Collector Cutoff Current	I <sub>CBO</sub>		50	nA µA	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0 V <sub>CB</sub> = 120V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C	
Emitter Cutoff Current	I <sub>EBO</sub>	_	50	nA	$V_{EB} = 4.0V, I_{C} = 0$	
ON CHARACTERISTICS (Note 7)						
		80	_		$I_C = 1.0 \text{mA}, V_{CE} = 5.0 \text{V}$	
DC Current Gain	h <sub>FE</sub>	80	250	_	$I_C = 10mA, V_{CE} = 5.0V$	
		30	_		$I_C = 50 \text{mA}, V_{CE} = 5.0 \text{V}$	
Collector-Emitter Saturation Voltage	V		0.15	V	$I_C = 10mA, I_B = 1.0mA$	
Collector-Emilier Saturation Voltage	V <sub>CE(sat)</sub>		0.20	V	$I_C = 50mA$ , $I_B = 5.0mA$	
Base-Emitter Saturation Voltage	V		1.0	V	$I_C = 10mA, I_B = 1.0mA$	
· ·	V <sub>BE(sat)</sub>		1.0	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	$C_{obo}$	_	6.0	pF	$V_{CB} = 10V$ , $f = 1.0MHz$ , $I_E = 0$	
Small Signal Current Gain	h <sub>fe</sub>	50	250		$V_{CE} = 10V, I_{C} = 1.0mA,$ f = 1.0kHz	
Current Gain-Bandwidth Product	f <sub>t</sub>	100	300	MHz	$V_{CE} = 10V, I_{C} = 10mA,$ f = 100MHz	
Noise Figure	nf		8.0	dB	$V_{CE} = 5.0V$ , $I_{C} = 200\mu A$ , $R_{S} = 1.0k\Omega$ , $f = 1.0kHz$	

Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
- 7. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



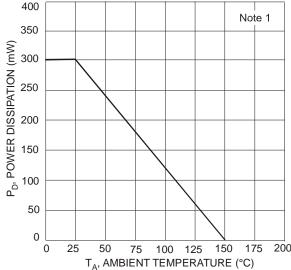


Fig. 1 Power Dissipation vs. Ambient Temperature

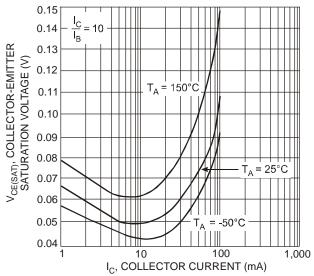


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

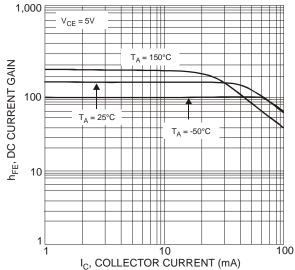


Fig. 2 Typical DC Current Gain vs. Collector Current

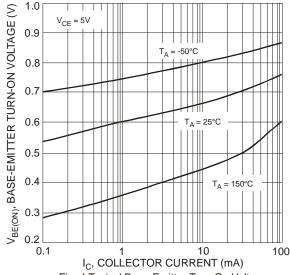


Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

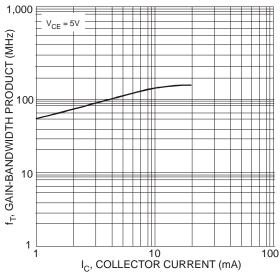
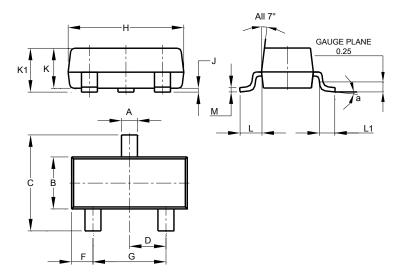


Fig. 5 Typical Gain-Bandwidth Product vs. Collector Current



# **Package Outline Dimensions**

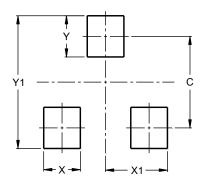
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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